FAIRCHILD SEMICONDUCTOR®

August 2013

LM431SA / LM431SB / LM431SC
Programmable Shunt Regulator

Features

- Programmable Output Voltage to 36 V
- Low Dynamic Output Impedance: 0.2 Ω (Typical)
- Sink Current Capability of 1.0 to 100 mA
- Equivalent Full-Range Temperature Coefficient of 50 ppm/°C(Typical)
- Temperature Compensated for Operation Over Full Rated Operating Temperature Range
- Low Output Noise Voltage
- Fast Turn-on Response

Description

The LM431SA / LM431SB / LM431SC are three-terminal the output adjustable regulators with thermal stability over operating temperature range. The output voltage can be set any value between V_{REF} (approximately 2.5 V) and 36 V with two external resistors. These devices have a typical dynamic output impedance of 0.2 Ω. Active output circuit provides a sharp turn-on characteristic, making these devices excellent replacement for Zener diodes in many applications.

SOT-89

1. Ref 2. Anode 3. Cathode

SOT-23F

1. Cathode 2. Ref 3. Anode

SOT-23

M32 - 1. Ref 2. Cathode 3. Anode
M3 - 1. Cathode 2. Ref 3. Anode

Ordering Information

Product Number	Output Voltage Tolerance	Operating Temperature	Top Mark	Package	Packing Method
LM431SACMFX	2%	-25 to +85°C	43A	SOT-23F 3L	Tape and Reel
LM431SACM3X			43L	SOT-23 3L	
LM431SACM32X			43G	SOT-23 3L	
LM431SBCMLX	1%		43B	SOT-89 3L	
LM431SBCMFX			43B	SOT-23F 3L	
LM431SBCM3X			43M	SOT-23 3L	
LM431SBCM32X			43H	SOT-23 3L	
LM431SCCMLX	0.5%		43C	SOT-89 3L	
LM431SCCMFX			43C	SOT-23F 3L	
LM431SCCM3X			43N	SOT-23 3L	
LM431SCCM32X			43J	SOT-23 3L	
LM431SAIMFX	2%	-40 to +85°C	43AI	SOT-23F 3L	

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Block Diagram

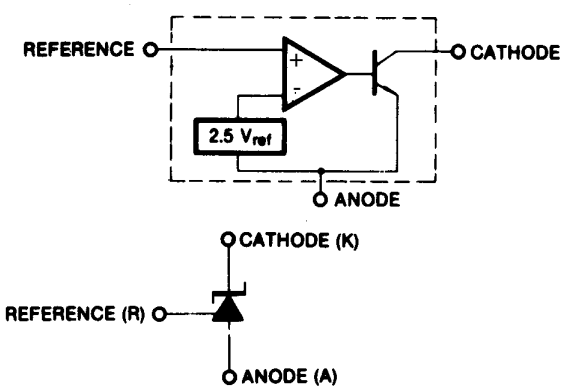

Figure 1. Block Diagram

Absolute Maximum Ratings

Stresses exceeding the absolute maximum ratings may damage the device. The device may not function or be operable above the recommended operating conditions and stressing the parts to these levels is not recommended. In addition, extended exposure to stresses above the recommended operating conditions may affect device reliability. The absolute maximum ratings are stress ratings only. Values are at T_A = 25°C unless otherwise noted.

Symbol	Parameter		Value	Unit
V_{KA}	Cathode Voltage		37	V
I_{KA}	Cathode current Range (Continuous)		-100 to +150	mA
I_{REF}	Reference Input Current Range		-0.05 to +10.00	mA
$R_{\theta JA}$	Thermal Resistance Junction-Air (1,2)	ML Suffix Package (SOT-89)	220	°C/W
		MF Suffix Package (SOT-23F)	350	
		M32, M3 Suffix Package (SOT-23)	400	
P_D	Power Dissipation (3,4)	ML Suffix Package (SOT-89)	560	mW
		MF Suffix Package (SOT-23F)	350	
		M32, M3 Suffix Package (SOT-23)	310	
T_J	Junction Temperature		150	°C
T_{OPR}	Operating Temperature Range	All products except LM431SAIMFX	-25 to +85	°C
		LM431SAIMFX	-40 to +85	
T_{STG}	Storage Temperature Range		-65 to +150	°C

Notes:

1. Thermal resistance test board
   Size: 1.6 mm x 76.2 mm x 114.3 mm (1S0P)
   JEDEC Standard: JESD51-3, JESD51-7.
2. Assume no ambient airflow.
3. T_{JMAX} = 150°C; ratings apply to ambient temperature at 25°C.
4. Power dissipation calculation: $P_D = (T_J - T_A) / R_{\theta JA}$.

Recommended Operating Conditions

Symbol	Parameter	Min.	Max.	Unit
V_{KA}	Cathode Voltage	V_{REF}	36	V
I_{KA}	Cathode Current	1	100	mA

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Electrical Characteristics

Values are at T_A = 25°C unless otherwise noted.

Symbol	Parameter	Conditions		LM431SA			LM431SB			LM431SC			Unit
				Min.	Typ.	Max.	Min.	Typ.	Max.	Min.	Typ.	Max.	
V_{REF}	Reference Input Voltage	$V_{KA} = V_{REF}$, I_{KA} = 10 mA		2.450	2.500	2.550	2.470	2.495	2.520	2.482	2.495	2.508	V
$\Delta V_{REF} / \Delta T$	Deviation of Reference Input Voltage Over-Temperature	$V_{KA} = V_{REF}$, I_{KA} = 10 mA $T_{MIN} \le T_A \le T_{MAX}$	SOT-89 SOT-23F		4.5	17.0		4.5	17.0		4.5	17.0	mV
			SOT-23		6.6	24		6.6	24		6.6	24	mV
$\Delta V_{REF} / \Delta V_{KA}$	Ratio of Change in Reference Input Voltage to the Change in Cathode Voltage	I_{KA} =10 mA	ΔV_{KA} = 10 V-V_{REF}		-1.0	-2.7		-1.0	-2.7		-1.0	-2.7	mV/V
			ΔV_{KA} = 36 V-10 V		-0.5	-2.0		-0.5	-2.0		-0.5	-2.0	
I_{REF}	Reference Input Current	I_{KA} = 10 mA, R_1 = 10 KΩ, R_2 = ∞			1.5	4.0		1.5	4.0		1.5	4.0	µA
$\Delta I_{REF} / \Delta T$	Deviation of Reference Input Current Over Full Temperature Range	I_{KA} = 10 mA, R_1 = 10 KΩ, R_2 = ∞, T_A = Full Range	SOT-89 SOT-23F		0.4	1.2		0.4	1.2		0.4	1.2	µA
			SOT-23		0.8	2.0		0.8	2.0		0.8	2.0	µA
$I_{KA(MIN)}$	Minimum Cathode Current for Regulation	$V_{KA} = V_{REF}$			0.45	1.00		0.45	1.00		0.45	1.00	mA
$I_{KA(OFF)}$	Off -Stage Cathode Current	V_{KA} = 36 V, V_{REF} = 0			0.05	1.00		0.05	1.00		0.05	1.00	µA
Z_{KA}	Dynamic Impedance	$V_{KA} = V_{REF}$, I_{KA} = 1 to 100 mA, f ≥ 1.0 kHz			0.15	0.50		0.15	0.50		0.15	0.50	Ω

Note:

5. T_{MIN} = -25°C, T_{MAX} = +85°C.

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Electrical Characteristics[6, 7] (Continued)

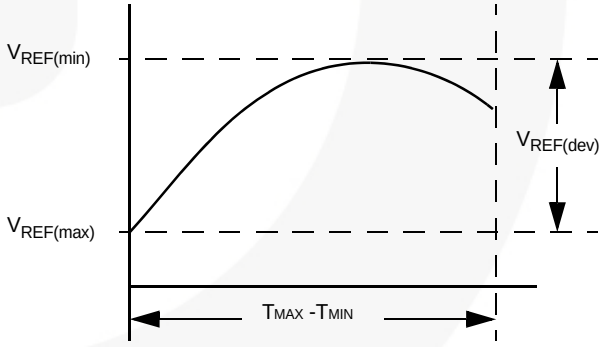
Values are at T_A = 25°C unless otherwise noted.

Symbol	Parameter	Conditions		LM431SAI			Unit
				Min.	Typ.	Max.	
V_{REF}	Reference Input Voltage	$V_{KA} = V_{REF}$, I_{KA} = 10 mA		2.450	2.500	2.550	V
$V_{REF(dev)}$	Deviation of Reference Input Voltage Over-Temperature	$V_{KA} = V_{REF}$, I_{KA} = 10 mA, $T_{MIN} \le T_A \le T_{MAX}$			5	20	mV
$\Delta V_{REF}/\Delta V_{KA}$	Ratio of Change in Reference Input Voltage to Change in Cathode Voltage	I_{KA} = 10 mA	ΔV_{KA} = 10 V - V_{REF}		-1.0	-2.7	mV/V
			ΔV_{KA} = 36 V - 10 V		-0.5	-2.0	
I_{REF}	Reference Input Current	I_{KA} = 10 mA, R_1 =10 KΩ, R_2 = ∞			1.5	4.0	µA
$I_{REF(dev)}$	Deviation of Reference Input Current Over Full Temperature Range	I_{KA} = 10 mA, R_1 = 10 KΩ, R_2 = ∞, $T_{MIN} \le T_A \le T_{MAX}$			0.8	2.0	µA
$I_{KA(MIN)}$	Minimum Cathode Current for Regulation	$V_{KA} = V_{REF}$			0.45	1.00	mA
$I_{KA(OFF)}$	Off -Stage Cathode Current	V_{KA} = 36 V, V_{REF} = 0			0.05	1.00	µA
Z_{KA}	Dynamic Impedance	$V_{KA} = V_{REF}$, I_{KA} = 1 to 100 mA, f ≥ 1.0 kHz			0.15	0.50	Ω

Notes:

6. T_{MIN} = -40°C, T_{MAX} = +85°C.
7. The deviation parameters $V_{REF(dev)}$ and $I_{REF(dev)}$ are defined as the differences between the maximum and minimum values obtained over the rated temperature range. The average full-range temperature coefficient of the reference input voltage, αV_{REF}, is defined as:

$$|\alpha V_{REF}|\left(\frac{ppm}{°C}\right) = \frac{\left(\frac{V_{REF(dev)}}{V_{REF}(at25°C)}\right) \cdot 10^6}{T_{MAX} - T_{MIN}}$$



where T_{MAX} -T_{MIN} is the rated operating free-air temperature range of the device.
αV_{REF} can be positive or negative, depending on whether minimum V_{REF} or maximum V_{REF}, respectively, occurs at the lower temperature.

Example: $V_{REF(dev)}$ = 4.5 mV, V_{REF} = 2500 mV at 25 °C, T_{MAX} -T_{MIN} = 125 °C for LM431SAI.

$$|\alpha V_{REF}| = \frac{\left(\frac{4.5mV}{2500mV}\right) \cdot 10^6}{125°C} = 14.4 ppm/°C$$

Because minimum V_{REF} occurs at the lower temperature, the coefficient is positive.

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Test Circuits

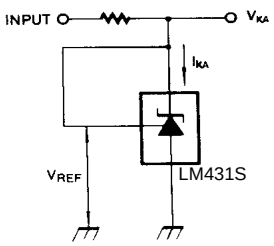

Figure 2. Test Circuit for $V_{KA} = V_{REF}$

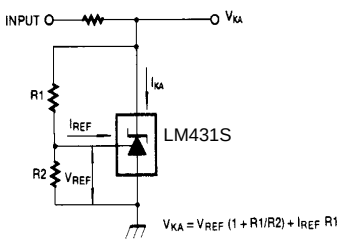

Figure 3. Test Circuit for $V_{KA} \geq V_{REF}$

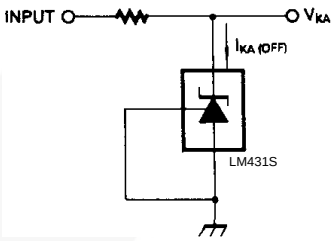

Figure 4. Test Circuit for $I_{KA(OFF)}$

Typical Performance Characteristics

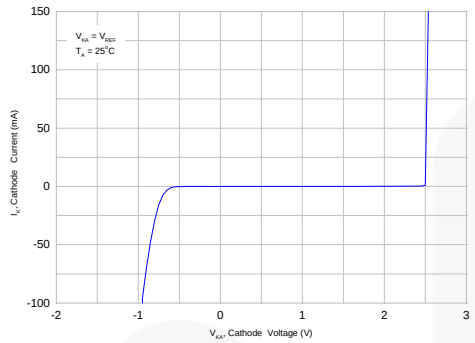

Figure 5. Cathode Current vs. Cathode Voltage

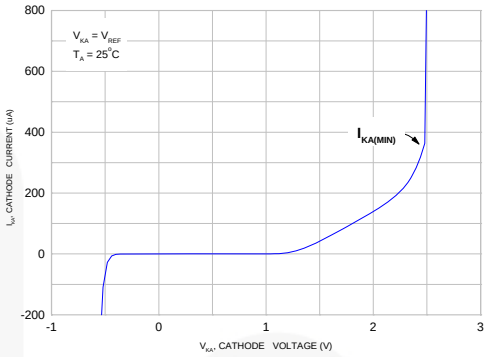

Figure 6. Cathode Current vs. Cathode Voltage

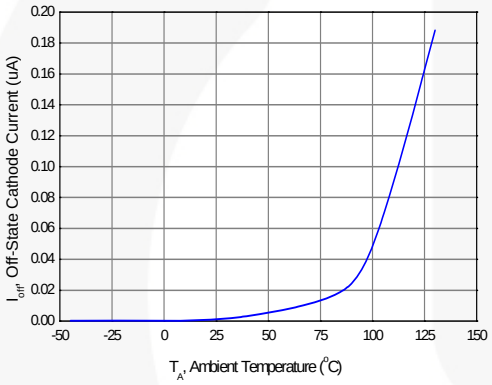

Figure 7. OFF-State Cathode Current vs. Ambient Temperature

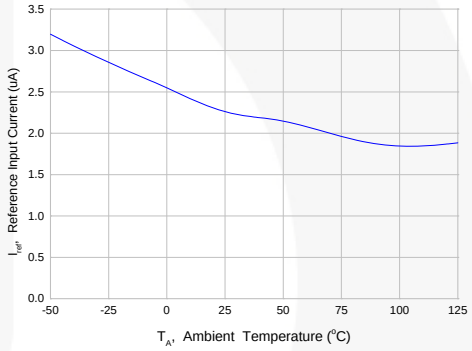

Figure 8. Reference Input Current vs. Ambient Temperature

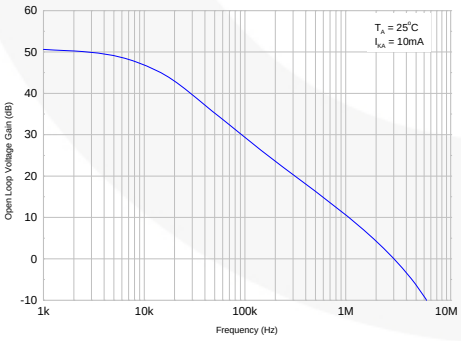

Figure 9. Frequency vs. Small Signal Voltage Amplification

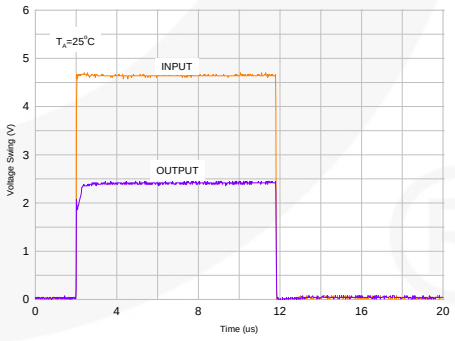

Figure 10. Pulse Response

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Typical Performance Characteristics (Continued)

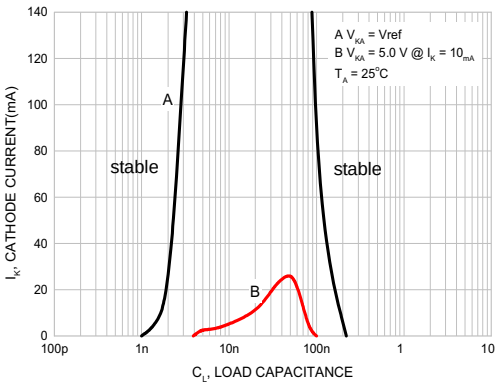

Figure 11. Stability Boundary Conditions

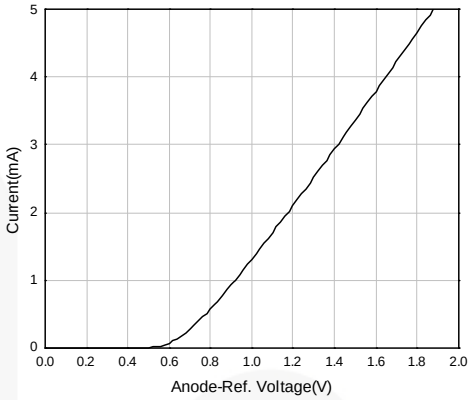

Figure 12. Anode-Reference Diode Curve

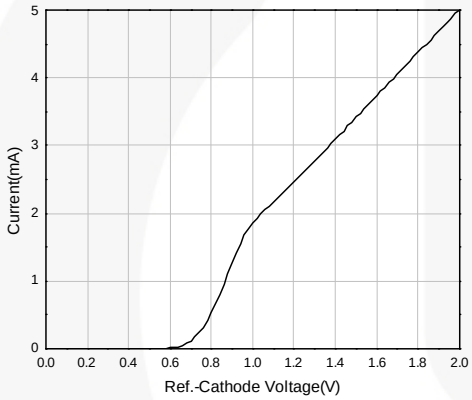

Figure 13. Reference-Cathode Diode Curve

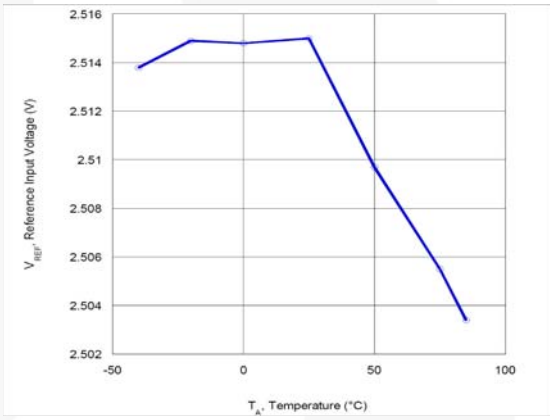

Figure 14. Reference Input Voltage vs. Ambient Temperature

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Typical Application

$$V_O = \left(1 + \frac{R_1}{R_2}\right) V_{ref}$$

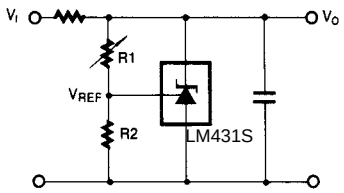

Figure 15. Shunt Regulator

$$V_O = V_{ref}\left(1 + \frac{R_1}{R_2}\right)$$

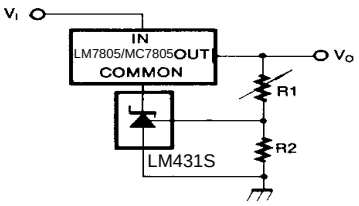

Figure 16. Output fir Three-Terminal Fixed Regulator

$$V_O = \left(1 + \frac{R_1}{R_2}\right) V_{ref}$$

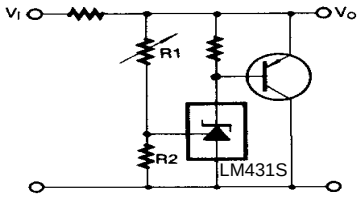

Figure 17. High Current Shunt Regulator

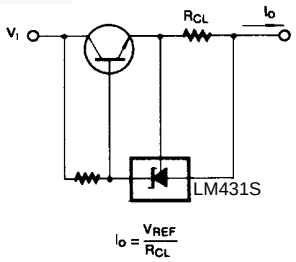

Figure 18. Current Limit or Current Source

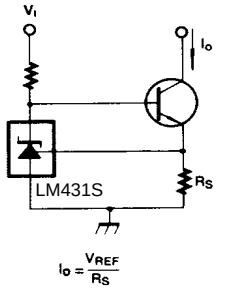

Figure 19. Constant-Current Sink

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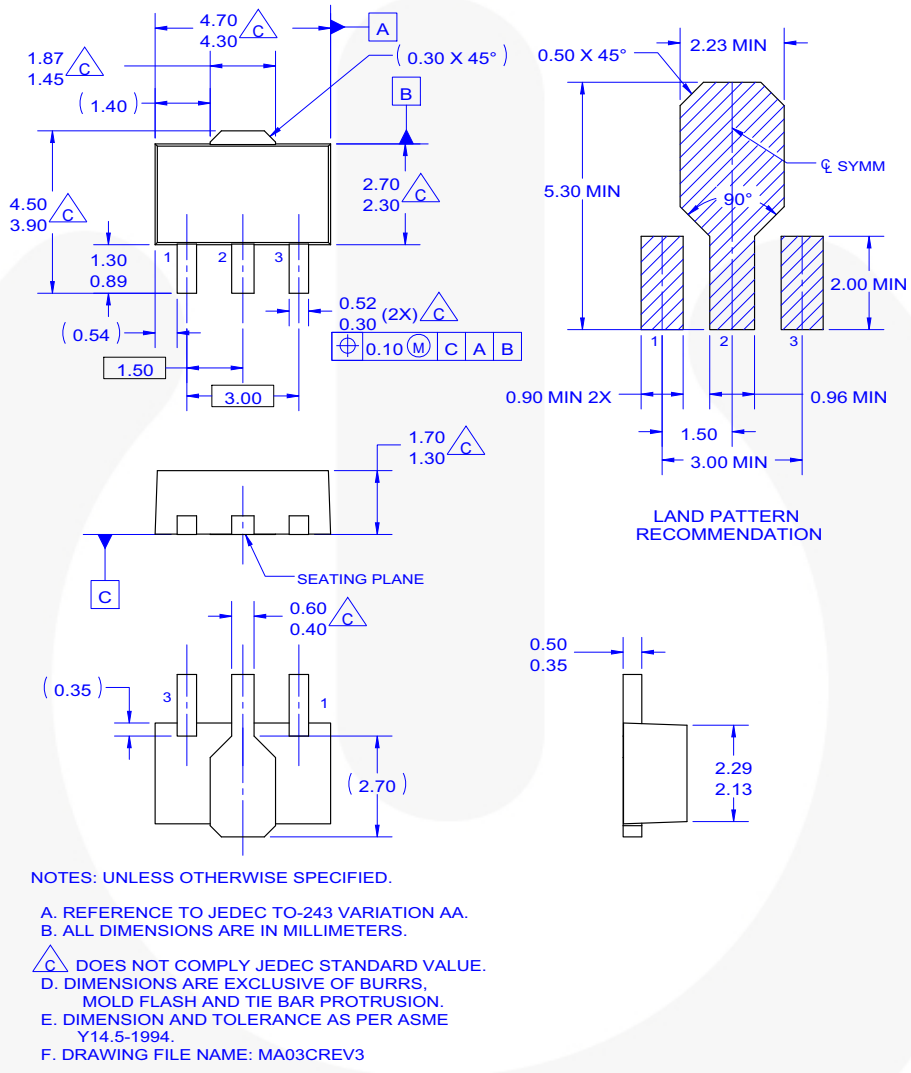
Physical Dimensions

SOT-89



NOTES: UNLESS OTHERWISE SPECIFIED.

A. REFERENCE TO JEDEC TO-243 VARIATION AA.
B. ALL DIMENSIONS ARE IN MILLIMETERS.
C DOES NOT COMPLY JEDEC STANDARD VALUE.
D. DIMENSIONS ARE EXCLUSIVE OF BURRS, MOLD FLASH AND TIE BAR PROTRUSION.
E. DIMENSION AND TOLERANCE AS PER ASME Y14.5-1994.
F. DRAWING FILE NAME: MA03CREV3

Figure 20. 3-LEAD, SOT-89, JEDEC TO-243, OPTION AA (ACTIVE)

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Physical Dimensions

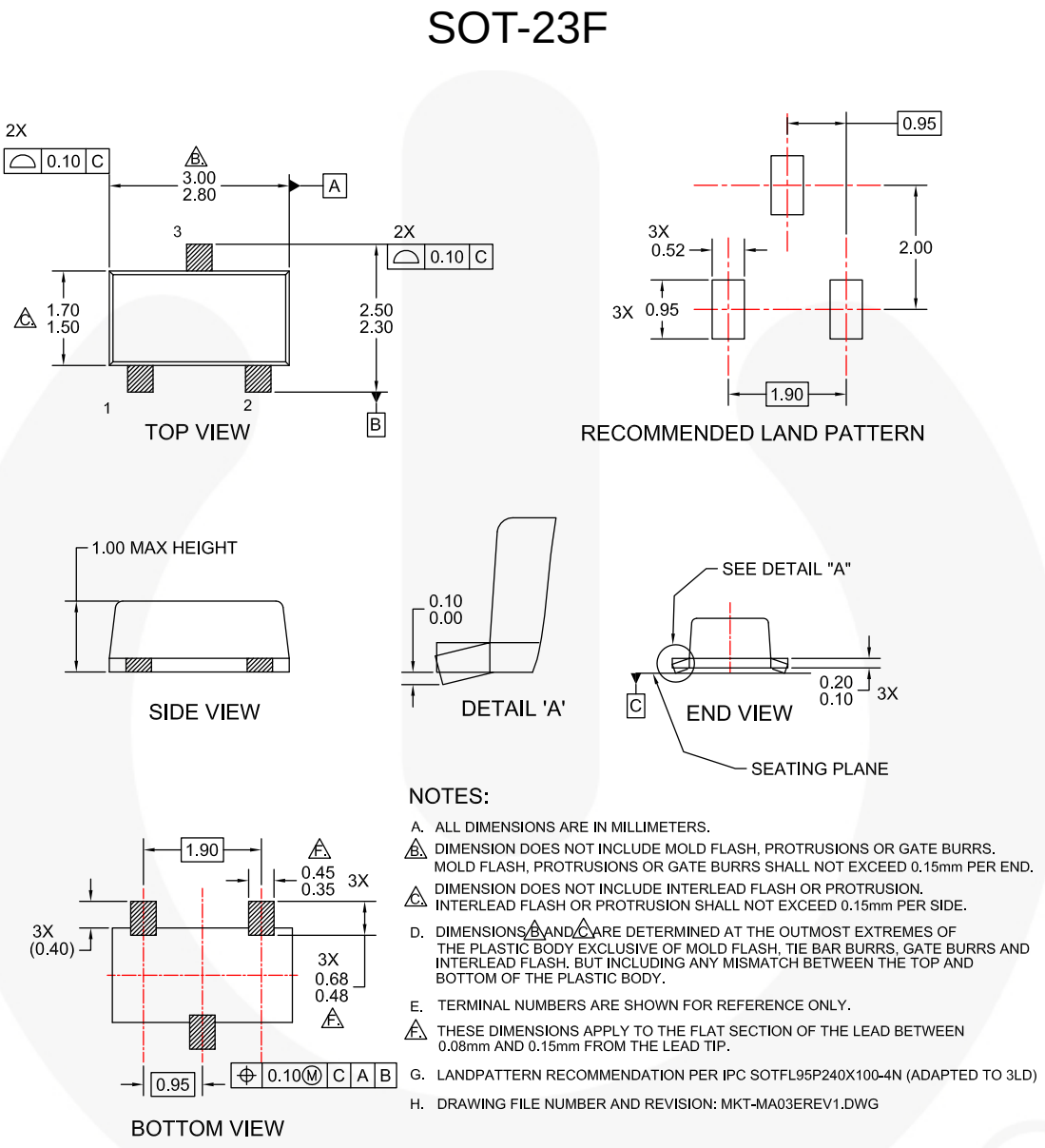

Figure 21. 3-LEAD, SOT-23, FLAT LEAD, LOW PROFILE (ACTIVE)

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Physical Dimensions

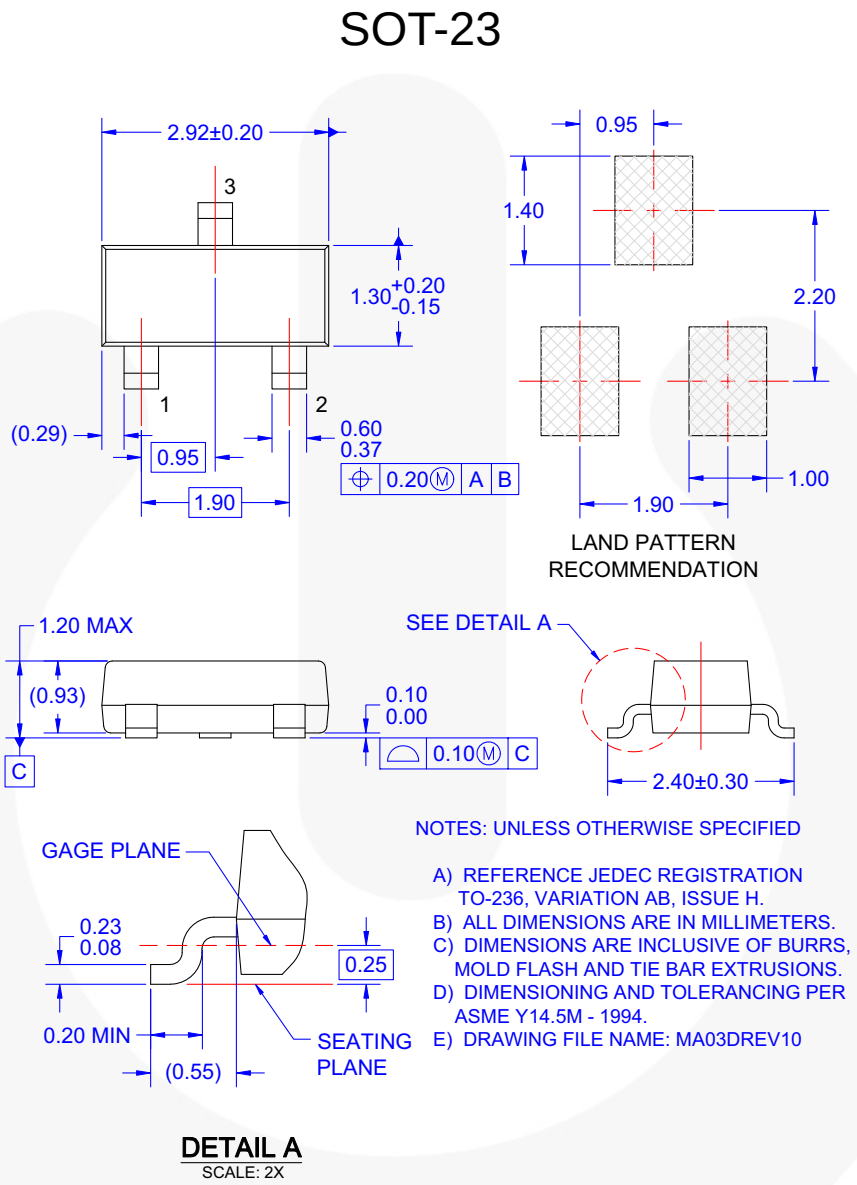

Figure 22. 3-LEAD, SOT-23, JEDEC TO-236, LOW PROFILE (ACTIVE)

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FRFET®
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Green FPS™ e-Series™
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ISOPLANAR™
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MegaBuck™
MICROCOUPLER™
MicroFET™
MicroPak™
MicroPak2™
MillerDrive™
MotionMax™
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OPTOPLANAR®
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SuperSOT™-6
SuperSOT™-8
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TinyLogic®
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As used herein:

1. Life support devices or systems are devices or systems which, (a) are intended for surgical implant into the body or (b) support or sustain life, and (c) whose failure to perform when properly used in accordance with instructions for use provided in the labeling, can be reasonably expected to result in a significant injury of the user.
2. A critical component in any component of a life support, device, or system whose failure to perform can be reasonably expected to cause the failure of the life support device or system, or to affect its safety or effectiveness.

ANTI-COUNTERFEITING POLICY

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PRODUCT STATUS DEFINITIONS

Definition of Terms

Datasheet Identification	Product Status	Definition
Advance Information	Formative / In Design	Datasheet contains the design specifications for product development. Specifications may change in any manner without notice.
Preliminary	First Production	Datasheet contains preliminary data; supplementary data will be published at a later date. Fairchild Semiconductor reserves the right to make changes at any time without notice to improve design.
No Identification Needed	Full Production	Datasheet contains final specifications. Fairchild Semiconductor reserves the right to make changes at any time without notice to improve the design.
Obsolete	Not In Production	Datasheet contains specifications on a product that is discontinued by Fairchild Semiconductor. The datasheet is for reference information only.

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